

FAN9673

Three-Channel Interleaved CCM PFC Controller

Description

The FAN9673 is an interleaved three-channel Continuous Conduction Mode (CCM) Power Factor Correction (PFC) controller IC intended for PFC pre-regulators. Incorporating circuits for the implementation of leading edge, average current, and “boost”-type power factor correction, the FAN9673 enables the design of a power supply that fully complies with the IEC1000-3-2 specification. Interleaved operation provides substantial reduction in the input and output ripple currents and the conducted EMI filtering becomes easier and cost effective.

An innovative channel management function allows slave channels to be loaded and unloaded smoothly in lower power-level conditions according to setting voltage on the CM pin, improving the PFC converter's load transient response.

The FAN9673 also incorporates a variety of protection functions, including: peak current limiting, input voltage brownout protection, and TriFault Detect function.

Features

- Continuous Conduction Mode Control
- Three-Channel PFC Control (Maximum)
- Average Current-Mode Control
- PFC Slave Channel Management Function
- Programmable Operation Frequency Range: 18 kHz ~ 40 kHz or 55 kHz ~ 75 kHz
- Programmable PFC Output Voltage
- Dual Current Limit Functions
- TriFault Detect Protects Against Feedback Loop Failure
- Sag Protection
- Programmable Soft-Start
- Under-Voltage Lockout (UVLO)
- Differential Current Sensing
- Available in 32-Pin LQFP Package

Typical Applications

- High Power AC-DC Power Supply
- DC Motor Power Supply
- White Goods; e.g. Air Conditioner Power Supply
- Server and Telecom Power Supply
- Industrial Welding and Power Supply



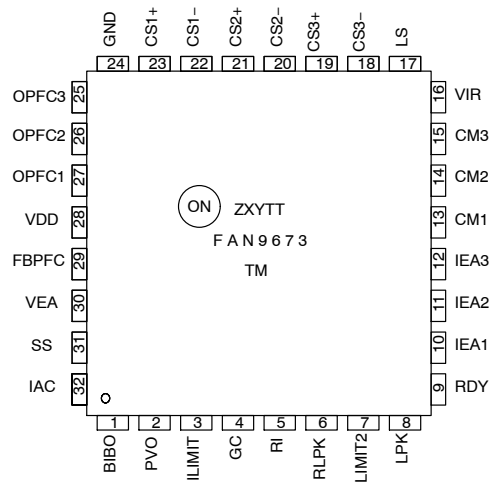
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LQFP32
CASE 561AB

MARKING DIAGRAM



Z = Assembly Plant Code
X = Year Code
Y = Work Code
TT = Die Run Code
T = Package Type (Q:LQFP)
M = Manufacture Flow Code

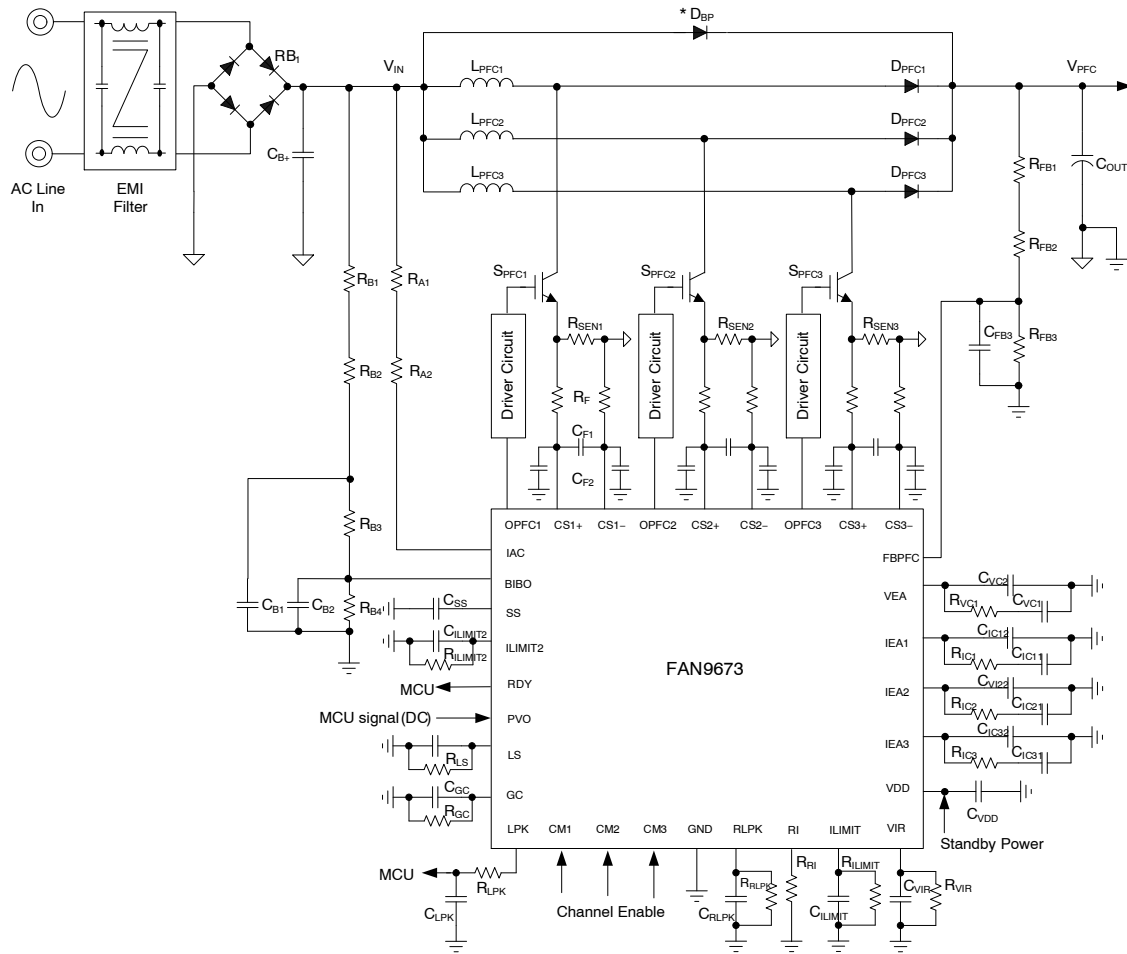
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

ORDERING INFORMATION

Part Number	Operating Temperature Range	Package	Packing Method
FAN9673Q	-40°C to 105°C	32LD, LQFP, JEDEC MS-026, Variation BBA, 7 mm Square	Tray
FAN9673QX			Tape & Reel

TYPICAL APPLICATION

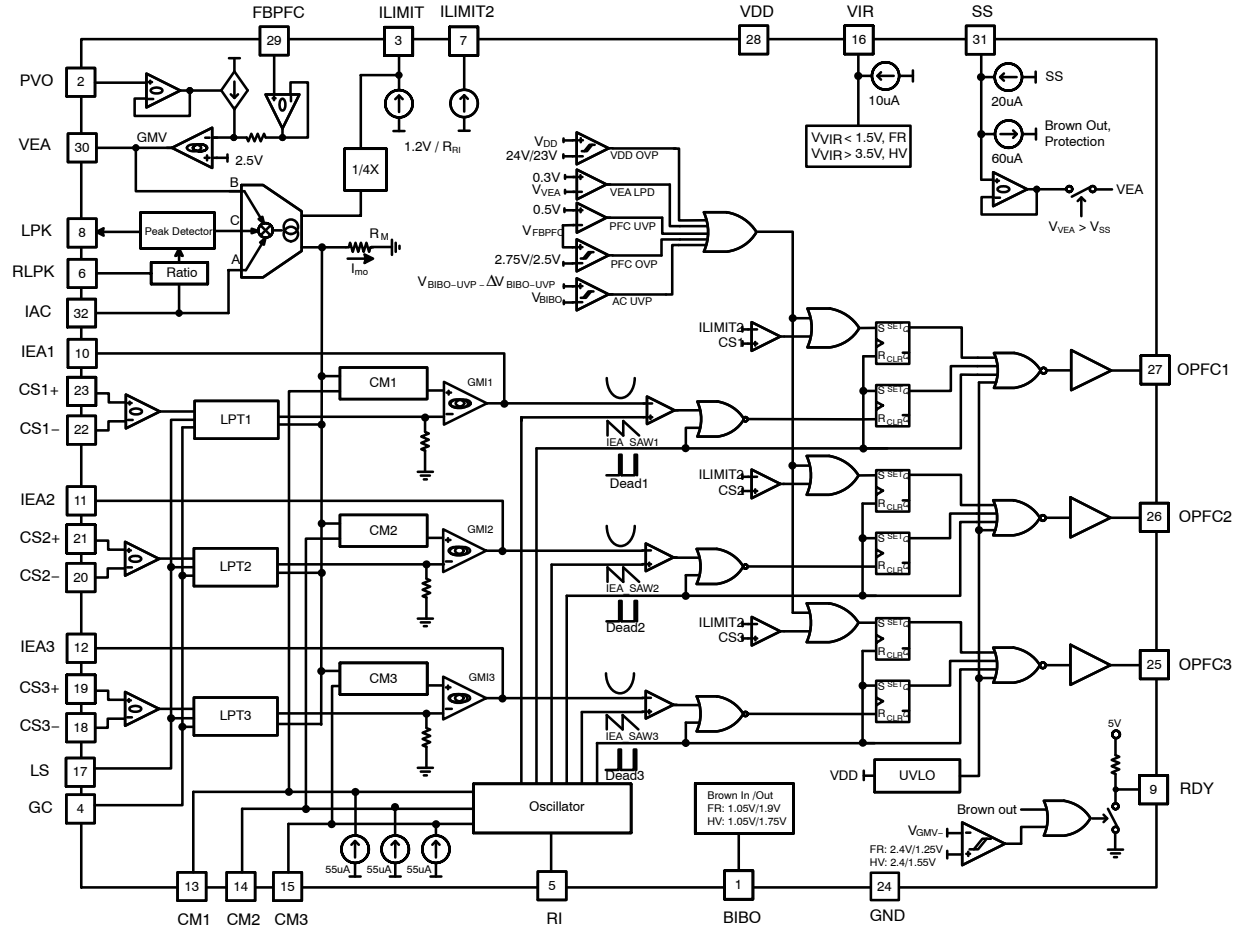


* About D_{BP} please reference System Design Precautions

Figure 1. Typical Application Diagram for Three-Channel PFC Converter

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BLOCK DIAGRAM



* FR: Full Range AC Input, AC85 V~264 V
HV: High Voltage Range AC Input, AC180 ~ 264 V

Figure 2. Functional Block Diagram

PIN CONFIGURATION

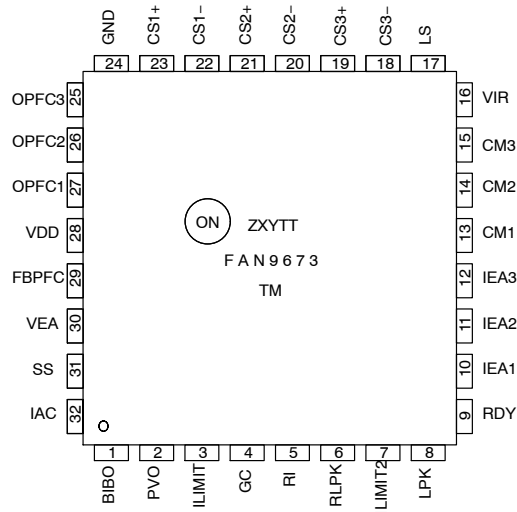


Figure 3. Pin Layout (Top View)

Table 1. PIN DEFINITIONS

Pin #	Name	Description
1	BIBO	Brown In/Out Level Setting: This pin is used for brown in/out setting.
2	PVO	Programmable Output Voltage: DC voltage from a microcontroller (MCU) can be applied to this pin to program the output voltage level. The operation range is 3.5 V ~ 0.5 V. If $V_{PO} < 0.5$ V, the PVO function is disabled.
3	ILIMIT	Current Command Clamp Setting: Average current mode is to control average value of inductor current by a current command. Connecting a resistor and a capacitor to this pin can determine a limit value of the current command.
4	GC	Input Voltage Gain Control: Connecting a resistor on this pin to set a gain on the input-voltage signal to match FBPFC. The signal here is used for the LPT function. A small capacitor connecting from GC to GND is recommended for noise filtering.
5	RI	Oscillator Setting: There are two oscillator frequency ranges: 18 ~ 40 kHz and 50 ~ 75 kHz. A resistor connected from RI to ground determines the switching frequency. A resistor value between 10.6 k ~ 44.4 k Ω is recommended.
6	RLPK	Ratio of V_{LPK} and V_{IN} : Connect a resistor and a capacitor to this pin to adjust the ratio of V_{IN} peak to V_{LPK} . Typical value is 12.4 k Ω (1:100 of V_{LPK} and V_{IN} peak). The accuracy of V_{LPK} is primarily determined by the tolerance of R_{RLPK} at this pin.
7	ILIMIT2	Peak Current Limit Setting: Connect a resistor and a capacitor to this pin to set the over-current limit threshold and to protect power devices from damage due to inductor saturation. This pin sets the over-current threshold for cycle-by-cycle current limit.
8	LPK	Peak of Line Voltage: This pin can be used to provide information about the peak amplitude of the line voltage to an MCU.
9	RDY	Output Ready Signal: When the feedback voltage on FBPFC exceeds 2.4 V, the RDY pin outputs a high-state V_{RDY} signal to inform the MCU the downstream power stage can start normal operation. If AC brownout is detected, the V_{RDY} signal is LOW to signal the MCU the PFC is not ready.
10	IEA1	Output 1 of PFC Current Amplifier: The signal from this pin is compared with an internal sawtooth signal to determine the pulse width for PFC gate drive 1.
11	IEA2	Output 2 of PFC Current Amplifier: The signal from this pin is compared with an internal sawtooth signal to determine the pulse width for PFC gate drive 2.
12	IEA3	Output 3 of PFC Current Amplifier: The signal from this pin is compared with an internal sawtooth signal to determine the pulse width for PFC gate drive 3.
13	CM1	Channel 1 Management Setting: This pin is used to configure the characteristics of PFC enable/disable. Pull voltage on this pin LOW (= 0 V) to enable and HIGH (> 4 V) to disable the whole PFC system.
14	CM2	Channel 2 Management Setting: There are two control methods for channel 2. The first uses an external signal to enable/disable channel 2 ($V_{CM2} = 0$ V/ $V_{CM2} > 4$ V). The second is linear increase/decrease loading of channel 2 when V_{VEA} , proportional to power level, meets the setting level on V_{CM2} .
15	CM3	Channel 3 Management Setting: Same as the CM2 pin, but for Channel 3.
16	VIR	Input Voltage Range Setting: A capacitor and a resistor are connected in parallel from this pin to GND. When $V_{VIR} > 3.5$ V, the PFC controller only works for the high-voltage input range (180 V _{AC} ~ 264 V _{AC}) and R_{IAC} must be 12 M Ω . When $V_{VIR} < 1.5$ V, the PFC controller works for the Universal Input voltage range (90 V _{AC} ~ 264 V _{AC}) and R_{IAC} must be 6 M Ω . Voltage between 1.5 V and 3.5 V is not allowed.
17	LS	Setting for Current Predict Function: A resistor, connected from this pin to ground, is used to adjust the compensation of linear predict function (LPT). A small capacitor connected from this pin to GND is recommended for noise filtering.
18	CS3-	Channel 3 Negative PFC Current Sense Input
19	CS3+	Channel 3 Positive PFC Current Sense Input
20	CS2-	Channel 2 Negative PFC Current Sense Input
21	CS2+	Channel 2 Positive PFC Current Sense Input
22	CS1-	Channel 1 Negative PFC Current Sense Input
23	CS1+	Channel 1 Positive PFC Current Sense Input
24	GND	Ground Reference and Return
25	OPFC3	Channel 3 PFC Gate Drive: The totem-pole output drive for the MOSFET or IGBT. This pin has an internal 15 V clamp to protect the external power switch.

Table 1. PIN DEFINITIONS (continued)

Pin #	Name	Description
26	OPFC2	Channel 2 PFC Gate Drive: The totem-pole output drive for the MOSFET or IGBT. This pin has an internal 15 V clamp to protect the external power switch.
27	OPFC1	Channel 1 PFC Gate Drive: The totem-pole output drive for the MOSFET or IGBT. This pin has an internal 15 V clamp to protect the external power switch.
28	VDD	External Bias Supply for the IC: The typical turn-on and turn-off threshold voltages are 12.8 V and 10.8 V respectively.
29	FBPFC	Voltage Feedback Input for PFC: Inverting input of the PFC error amplifier. This pin is connected to the PFC output through a resistor-divider network.
30	VEA	Output of PFC Voltage-Loop Amplifier: An error-amplifier output for the PFC voltage feedback loop. A compensation network is connected between this pin and ground.
31	SS	Soft-Start: Connect a capacitor to this pin to set the soft-start time. Pulling this pin to ground can disable the gate drive outputs OPFC1, OPFC2 and OPFC3.
32	IAC	Input AC Current: During normal operation, this input provides a current reference for an internal gain modulator. The recommended maximum current on IAC is 65 μ A.

ABSOLUTE MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter		Min	Max	Unit
V_{DD}	DC Supply Voltage			30	V
V_{OPFC}	Voltage on OPFC1, OPFC2, OPFC3 Pins		-0.3	$V_{DD} + 0.3$ V	V
V_L	Voltage on IAC, BIBO, LPK RLPK, FBPFC, VEA, CS1+, CS2+, CS3+, CS1-, CS2-, CS3-, CM1, CM2, CM3, ILIMIT, ILIMIT2, RI, PVO, GC, LS, VIR Pins		-0.3	7.0	V
V_{IEA}	Voltage on IEA1, IEA2, IEA3, SS Pins		0	8	V
I_{IAC}	Input AC Current			1	mA
$I_{PFC-OPFC}$	Peak PFC OPFC Current, Source or Sink			0.5	A
P_D	Power Dissipation, $T_A < 50^\circ\text{C}$			1640	mW
$R_{\theta J-A}$	Thermal Resistance (Junction-to-Air)			77	$^\circ\text{C/W}$
T_J	Operating Junction Temperature		-40	150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range		-55	150	$^\circ\text{C}$
T_L	Lead temperature (Soldering)			260	$^\circ\text{C}$
ESD	Electrostatic Discharge Capability	Human Body Model, ANSI/ESDA/JEDEC JS-001-2012		4	kV
		Charged Device Model, JESD22-C101		2	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Unit
V_{DD-OP}	Operating Voltage		15		V
$L_{MISMATCH}$	Boost Inductor Mismatch	-5		+5	%

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. All voltage values, except differential voltage, are given with respect to GND pin.
2. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.

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ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $V_{DD} = 15\text{ V}$ and $T_J = -40\sim 105^\circ\text{C}$)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
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VDD SECTION

$I_{DD\text{-}ST}$	Startup Current	$V_{DD} = V_{TH\text{-}ON} - 0.1\text{ V}$		30	80	μA
$I_{DD\text{-}OP}$	Operating Current	$V_{DD} = 14\text{ V}$, Output Not Switching, $R_{RI} = 25\text{ k}\Omega$	4	6	7	mA
$V_{TH\text{-}ON}$	Turn-On Threshold Voltage	V_{DD} Rising	11.7	12.8	13.9	V
ΔV_{TH}	UVLO Hysteresis		2		3	V
$V_{DD\text{-}OVP}$	V_{DD} OVP Threshold	OPFC1~3 Disabled, IEA1~3 and SS Pull Low	23	24	25	V
$\Delta V_{DD\text{-}OVP}$	V_{DD} OVP Hysteresis			1		V
$t_{D\text{-}OVP}$	V_{DD} OVP Debounce Time				80	μs

OSCILLATOR (Note 3)

V_{RI}	Sourcing Voltage on RI	$R_{RI} = 25\text{ k}\Omega$	1.15	1.20	1.25	V
f_{OSC1}	PFC Frequency Test Case 1	$R_{RI} = 25\text{ k}\Omega$	30	32	34	kHz
f_{OSC2}	PFC Frequency Test Case 2	$R_{RI} = 12.5\text{ k}\Omega$	58	62	66	kHz
f_{DV}	Voltage Stability	$13\text{ V} \leq V_{DD} \leq 22\text{ V}$			2	$\%$
f_{DT}	Temperature Stability				2	$\%$
$\Delta V_{IEA\text{-}SAW32}$	$V_{IEA\text{-}SAW}$ of PFC Frequency 32 kHz	$R_{RI} = 25\text{ k}\Omega$		5		V
$\Delta V_{IEA\text{-}SAW64}$	$V_{IEA\text{-}SAW}$ of PFC Frequency 64 kHz	$R_{RI} = 12.5\text{ k}\Omega$		5.15		V
$D_{PFC\text{-}MAX}$	Maximum Duty Cycle	$V_{IEA} > 7\text{ V}$	94	97		$\%$
$D_{PFC\text{-}MIN}$	Minimum Duty Cycle	$V_{IEA} < 1\text{ V}$			0	$\%$
f_{RANGE1}	Frequency Range 1 (Notes 3, 4)		18		40	kHz
f_{RANGE2}	Frequency Range 2 (Notes 3, 4)		55		75	kHz
$t_{DEAD\text{-}MIN}$	Minimum Dead Time	$R_{RI} = 10.7\text{ k}\Omega$		600		ns

INPUT-RANGE SETTING (VIR)

$V_{VIR\text{-}H}$	HIGH Setting Level for High Voltage Input Range	$R_{VIR} = 500\text{ k}\Omega$ ($V_{VIR} = 5\text{ V}$)	3.5			V
$V_{VIR\text{-}L}$	LOW Setting Level for Low Voltage Input Range or Full Voltage Input Range	$V_{VIR} = 0\text{ V}$			1.5	V
I_{VIR}	Sourcing Current of VIR Pin		7	10	13	μA

PFC SOFT-START

I_{SS}	Constant Current Output for Soft-Start	System Brown-in		22		μA
V_{SS}	Maximum Voltage on SS		6.8			V
$I_{SS\text{-}Discharge}$	Discharge Current of SS Pin	Brownout, SAG, $V_{CM1} > 4\text{ V}$, R_{RI} Open / Short, OTP		60		μA

VOLTAGE ERROR AMPLIFIER

V_{REF}	Reference Voltage	$PVO = GND$, $T_J = 25^\circ\text{C}$	2.45	2.50	2.55	V
A_V	Open-Loop Gain (Note 3)		42	65		dB
G_{mv}	Transconductance	$V_{NONINV} - V_{INV} = 0.5\text{ V}$, $T_J = 25^\circ\text{C}$		100		μS
$I_{FBPFC\text{-}L}$	Maximum Source Current	$V_{FBPFC} = 2\text{ V}$, $V_{VEA} = 3\text{ V}$	40	50		μA
$I_{FBPFC\text{-}H}$	Maximum Sink Current	$V_{FBPFC} = 3\text{ V}$, $V_{VEA} = 3\text{ V}$		-50	-40	μA
I_{BS}	Input Bias Current Range		-1		1	μA
$I_{FBPFC\text{-}FL}$	Pull High Current for FBPFC	FBPFC Floating		500		nA
$V_{VEA\text{-}H}$	Output High Voltage on V_{VEA}	$V_{FBPFC} = 2\text{ V}$	5.7	6.0		V
$V_{VEA\text{-}L}$	Output Low Voltage on V_{VEA}	$V_{FBPFC} = 3\text{ V}$		0	0.15	V

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ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $V_{DD} = 15\text{ V}$ and $T_J = -40\sim 105^\circ\text{C}$)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
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VOLTAGE ERROR AMPLIFIER

$I_{VEA-DIS}$	Discharge Current	Brownout, R_{RI} Open /Short, OTP, SAG		10		μA
$V_{VEA-OFF}$	Threshold Voltage for Low-Power Detection	When $V_{VEA} < V_{VEA-OFF}$, $V_{OPFC1\sim 3}$ are Off & $V_{IEA1\sim 3}$ are Pulled Low		0.3		V

CURRENT ERROR AMPLIFIERS

G_{mi}	Transconductance	$V_{NONINV} = V_{INV}$, $V_{IEA} = 4\text{ V}$, $V_{ILIMIT} > 0.6\text{ V}$, $T_J = 25^\circ\text{C}$		88		μS
V_{OFFSET}	Input Offset Voltage	$V_{VEA} = 0.45\text{ V}$, $R_{IAC} = 12\text{ M}\Omega$, $V_{IAC} = 311\text{ V}$, $V_{FBPFC} = 2\text{ V}$, $V_{VIR} > 5\text{ V}$, $T_J = 25^\circ\text{C}$		0		mV
V_{IEA-H}	Output High Voltage		6.8	7.0		V
V_{IEA-L}	Output Low Voltage			0	0.4	V
I_L	Sourcing Current	$V_{NONINV} - V_{INV} = +0.6\text{ V}$, $V_{IEA} = 1\text{ V}$, $V_{ILIMIT} > 0.6\text{ V}$	35	50		μA
I_H	Sinking Current	$V_{NONINV} - V_{INV} = -0.6\text{ V}$, $V_{IEA} = 6.5\text{ V}$, $V_{ILIMIT} > 0.6\text{ V}$		-50	-35	μA
A_I	Open-Loop Gain (Note 3)		40	50		dB
$I_{IEA-LOW}$	IEA Pin Pull-Low Capability	$V_{IEA} \geq 5\text{ V}$	500			μA

GAIN MODULATOR (Current Command Generator)

I_{AC}	Input for AC Current (Notes 3, 5)	Multiplier Linear Range	0		65	μA
BW	Bandwidth (Notes 3, 5)	$I_{AC} = 40\text{ }\mu\text{A}$		2		kHz
V_{RM}	Gain Modulator Output ($I_{MO} * R_M$) Test Cases	$V_{IAC} = 106.07\text{ V}$, $R_{IAC} = 6\text{ M}\Omega$, $V_{FBPFC} = 2.25\text{ V}$, $V_{BIBO} = 2\text{ V}$, V_{CM2} , $V_{CM3} > 4.5\text{ V}$, $T_J = 25^\circ\text{C}$		0.490		V
		$V_{IAC} = 120.21\text{ V}$, $R_{IAC} = 6\text{ M}\Omega$, $V_{FBPFC} = 2.25\text{ V}$, $V_{BIBO} = 2\text{ V}$, V_{CM2} , $V_{CM3} > 4.5\text{ V}$, $T_J = 25^\circ\text{C}$		0.430		
		$V_{IAC} = 155.56\text{ V}$, $R_{IAC} = 6\text{ M}\Omega$, $V_{FBPFC} = 2.25\text{ V}$, $V_{BIBO} = 2\text{ V}$, V_{CM2} , $V_{CM3} > 4.5\text{ V}$, $T_J = 25^\circ\text{C}$		0.327		
		$V_{IAC} = 311.13\text{ V}$, $R_{IAC} = 12\text{ M}\Omega$, $V_{FBPFC} = 2.25\text{ V}$, $V_{BIBO} = 2\text{ V}$, V_{CM2} , $V_{CM3} > 4.5\text{ V}$, $V_{VIR} > 3.5\text{ V}$, $T_J = 25^\circ\text{C}$		0.320		
		$V_{IAC} = 373.35\text{ V}$, $R_{IAC} = 12\text{ M}\Omega$, $V_{FBPFC} = 2.25\text{ V}$, $V_{BIBO} = 2\text{ V}$, V_{CM2} , $V_{CM3} > 4.5\text{ V}$, $V_{VIR} > 3.5\text{ V}$, $T_J = 25^\circ\text{C}$		0.260		
R_M	Resistor of Gain Modulator Output	$R_M = V_{RM} / I_{MO}$		7.5		k Ω

ILIMIT (Current Command Limit)

V_{RM-R}	Range of Peak Value in Current Command ($V_{ILIMIT}/4$)		0.2		0.8	V
$V_{RM-ILIMIT}$	Current Command Limit Test Case	$R_{ILIMIT} = 42\text{ k}\Omega$, $R_{RI} = 25\text{ k}\Omega$, $V_{RM-LIMIT} = R_{ILIMIT} * I_{ILIMIT}/4$		0.504		V
I_{ILIMIT}	Sourcing Current of ILIMIT Pin	$R_{RI} = 25\text{ k}\Omega$		49		μA

ILIMIT2 (CS1 /CS2 /CS3, Pulse-by-Pulse Current Limit)

$V_{ILIMIT2-CS1}$	Peak Current Limit Voltage Test Case	$R_{ILIMIT2} = 30\text{ k}\Omega$, $R_{RI} = 25\text{ k}\Omega$, $CS1\sim 3 > V_{ILIMIT2}$, $OPFC1$ Disables, $V_{IEA1\sim 3}$ Pull Low		1.48		V
$V_{ILIMIT2-CS2}$				1.48		V
$V_{ILIMIT2-CS3}$				1.48		V
$I_{ILIMIT2}$	Sourcing Current for ILIMIT2 Pin	$R_{RI} = 25\text{ k}\Omega$, $T_J = 25^\circ\text{C}$		49.5		μA

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ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $V_{DD} = 15\text{ V}$ and $T_J = -40\sim 105^\circ\text{C}$)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
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ILIMIT2 (CS1 /CS2 /CS3, Pulse-by-Pulse Current Limit)

$t_{PFC-BNK1}$	Leading-Edge Blanking Time of ILIMIT of Each Channel	$V_{DD} = 15\text{ V}$, OPFC Drops to 9 V		250		ns
$t_{PFC-BNK2}$				250		ns
$t_{PFC-BNK3}$				250		ns
t_{PD1}	Propagation Delay to Output of Each Channel			200	400	ns
t_{PD2}				200	400	ns
t_{PD3}				200	400	ns
$V_{ILIMIT2-OPEN}$	Threshold of ILIMIT2 Open-Circuit Protection	OPFC1~3 Disabled and $V_{IEA1\sim 3}$ Pull Low	3.8	4.0	4.2	V

TriFault Detect™

$V_{PFC-UVF}$	FBPFC Under-Voltage Protection		0.4	0.5	0.6	V
$V_{PFC-OVP}$	FBPFC Over-Voltage Protection (OVP)		2.70	2.75	2.80	V
$\Delta V_{PFC-OVP}$	FBPFC OVP		200	250	300	mV
$t_{FBPFC-OPEN}$	FBPFC Open Delay (Note 3)	$V_{FBPFC} = V_{PFC-UVF}$ to FBPFC Open, 470 pF from FBPFC to GND		2		ms
$t_{FBPFC-UVF}$	Under-Voltage Protection Debounce Time			50		μs

PVO

V_{PVO}	Programmable Output Setting Range on PVO Pin		0.3		3.5	V
V_{PVO_DIS}	PVO Disable Voltage	$PVO < V_{PVO_DIS}$		0.2		V
$V_{PVO-CLAMP}$	Low-clamp of FBPFC based on PVO	FBPFC Connected to VEA, $V_{PVO} = 4\text{ V}$		1.6		V
V_{FBPFC1}	FBPFC Voltage Test Cases	FBPFC Connected to VEA, $V_{PVO} = 0.3\text{ V}$		2.425		V
V_{FBPFC2}		FBPFC Connected to VEA, $V_{PVO} = 3.5\text{ V}$		1.625		V
$I_{PVO-Discharge}$	PVO Discharge Current	PVO Open		1		μA

GAIN COMPENSATION (GC) SECTION (Note 6)

I_{GC-L1}	Test Cases of Mirror Current of I_{AC} on GC Pin	$V_{VIR} = 0\text{ V}$, $V_{IAC} = 127.28\text{ V}$, $R_{IAC} = 6\text{ M}\Omega$,		20.71		μA
I_{GC-L2}		$V_{VIR} = 0\text{ V}$, $V_{IAC} = 311.13\text{ V}$, $R_{IAC} = 6\text{ M}\Omega$,		51.86		μA
I_{GC-HV}		$V_{VIR} = 5\text{ V}$, $V_{IAC} = 311.13\text{ V}$, $R_{IAC} = 12\text{ M}\Omega$.		51.86		μA
$I_{GC-OPEN}$	Pull High Current for GC-Pin Open			100		nA
$V_{GC-OPEN}$	GC-Pin Open Voltage	$V_{GC} > V_{GC-OPEN}$ V_{IEA} , OPFC1, 2, 3 Blanking	2.85	3.00	3.15	V

INDUCTANCE SETTING (LS) SECTION (Note 6)

R_{LS}	Acceptable Range of Inductance Setting		12		87	k Ω
V_{LS-MIN}	Voltage Difference between V_{FBPFC} and V_{GC} on LS Pin	$V_{FBPFC} - V_{GC} \geq 0\text{ V}$		50		mV

BROWN IN /OUT

$V_{BIBO-FL}$	Threshold of Brown-out at $V_{IR}=\text{LOW}$ Setting (Full AC-Input Range)	$V_{VIR} < 1.5\text{ V}$, $R_{IAC} = 6\text{ M}\Omega$	1.00	1.05	1.10	V
ΔV_{BIBO-F}	Hysteresis	$V_{BIBO} > V_{BIBO-FL} + \Delta V_{BIBO-F}$, Brown-in, Start SS		850		mV
$V_{BIBO-HL}$	Threshold of BO at $V_{IR}=\text{HIGH}$ Setting (High AC-Input Range)	$V_{VIR} > 3.5\text{ V}$, $R_{IAC} = 12\text{ M}\Omega$	1.00	1.05	1.10	V
ΔV_{BIBO-H}	Hysteresis	$V_{BIBO} > V_{BIBO-HL} + \Delta V_{BIBO-H}$, Brown-in, Start SS		700		mV
t_{UVP}	Under-Voltage Protection Delay Time			450		ms

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ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $V_{DD} = 15\text{ V}$ and $T_J = -40\sim 105^\circ\text{C}$)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
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SAG PROTECTION SECTION

V_{SAG}	SAG Voltage of BIBO	1. $V_{BIBO} < V_{SAG}$ & V_{RDY} High for 33 ms, or 2. $V_{BIBO} < V_{SAG}$ & V_{RDY} Low, Brownout,		0.85		V
t_{SAG-DT}	SAG Debounce Time	$V_{BIBO} < V_{SAG}$ & V_{RDY} High		33		ms

RLPK, VOLTAGE-SETTING RESISTANCE FOR PEAK DETECTOR

$I_{RLPK-OPEN}$	Pull High Current for RLPK Open			100		nA
$V_{RLPK-OPEN}$	Threshold of RLPK-pin Open-Circuit Protection	RLPK Open	2.28	2.40	2.52	V

LPK, PEAK-DETECTOR OUTPUT (Note 7)

V_{LPK-H1}	V_{LPK} Output Test Cases	$V_{IAC} = 311\text{ V}$, $R_{IAC} = 1\text{ M}\Omega$, $V_{VIR} > 3.5\text{ V}$, $R_{LPK} = 12.4\text{ k}\Omega$, $T_J = 25^\circ\text{C}$		3.168		V
V_{LPK-H2}		$V_{IAC} = 373\text{ V}$, $R_{IAC} = 12\text{ M}\Omega$, $V_{VIR} > 3.5\text{ V}$, $R_{LPK} = 12.4\text{ k}\Omega$, $T_J = 25^\circ\text{C}$		3.80		V
V_{LPK-L1}		$V_{IAC} = 127\text{ V}$, $R_{IAC} = 6\text{ M}\Omega$, $V_{VIR} < 1.5\text{ V}$, $R_{LPK} = 12.4\text{ k}\Omega$, $T_J = 25^\circ\text{C}$		1.29		V
V_{LPK-L2}		$V_{IAC} = 373\text{ V}$, $R_{IAC} = 6\text{ M}\Omega$, $V_{VIR} < 1.5\text{ V}$, $R_{LPK} = 12.4\text{ k}\Omega$, $T_J = 25^\circ\text{C}$		3.80		V
V_{AC-OFF}	AC OFF Threshold Voltage Test Case	$V_{IAC} = 373\text{ V}$, $R_{IAC} = 12\text{ M}\Omega$, $V_{VIR} > 3.5\text{ V}$ After t_{AC-OFF} V_{IEA} Pull Low		32		V
V_{AC-ON}	AC ON Threshold Voltage Test Case	$V_{IAC} = 373\text{ V}$, $R_{IAC} = 12\text{ M}\Omega$, $V_{VIR} > 3.5\text{ V}$		$V_{AC-OFF} + 26$		V

CM1 SECTION

I_{CM1}	CM1 Sourcing Current			55		μA
$V_{CM1-disable}$	PFC Disable Voltage	$I_{CM1} * R_{CM1} > 4\text{ V}$ OPFC1~3 Disabled and IEA1~3 Pull Low and SS Pull Low		4		V
θ_1	Phase of OPFC1	When $I_{CM1} * R_{CM1} < 4\text{ V}$ or Short		0		$^\circ$
θ_2	Phase of OPFC2 (Note 8)		110	120	130	$^\circ$
θ_3	Phase of OPFC3 (Note 8)		230	240	250	$^\circ$

CM2 SECTION

I_{CM2}	CM2 Sourcing Current			55		μA
$V_{CM2-disable}$	Channel-2 Disable Voltage	$I_{CM2} * R_{CM2} > 4\text{ V}$ or CM2 Floating OPFC2 Disables and IEA2 Pulls Low		4		V
$V_{CM2-range}$	Set VEA Unload Voltage		0		3.8	V
θ_1	Phase of OPFC1 (Note 8)	$I_{CM2} * R_{CM2} > 4\text{ V}$ or CM2 Floating		0		$^\circ$
θ_3	Phase of OPFC3 (Note 8)		170	180	190	$^\circ$

CM3 SECTION

I_{CM3}	CM3 Output Current			55		μA
$V_{CM3-disable}$	Channel-3 Disable Voltage	$I_{CM3} * R_{CM3} > 4\text{ V}$ or CM3 Floating OPFC3 Disables and IEA3 Pulls Low		4		V
$V_{CM3-range}$	Set VEA Unload Voltage		0		3.8	V
θ_1	Phase of OPFC1 (Note 8)	When $I_{CM3} * R_{CM3} > 4\text{ V}$ or CM3 Floating		0		$^\circ$
θ_2	Phase of OPFC2 (Note 8)		170	180	190	$^\circ$

ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $V_{DD} = 15\text{ V}$ and $T_J = -40\sim 105^\circ\text{C}$)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
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RDY SECTION

V_{FB-RD}	Level of V_{FBPFC} to Pull RDY High	$V_{PVO} = 0\text{ V}$, Brown-in, $V_{FBPFC} > V_{FB-RD}$	2.3	2.4	2.5	V
$\Delta V_{FB-RD-L}$	Hysteresis	$V_{PVO} = 0\text{ V}$, $V_{IR} < 1.5\text{ V}$		1.15		V
$\Delta V_{FB-RD-H}$	Hysteresis	$V_{PVO} = 0\text{ V}$, $V_{IR} > 3.5\text{ V}$		0.85		V
Z_{RDY}	Pull High Input Impedance	$T_J = 25^\circ\text{C}$		100		k Ω
$V_{RDY-High}$	HIGH Voltage of RDY		4.8	5.0		V
$V_{RDY-Low}$	LOW Voltage of RDY	Pull High Current = 1 mA			0.5	V

PFC OUTPUT DRIVER 1~3

$V_{GATE-CLAMP}$	Gate Output Clamping Voltage	$V_{DD} = 22\text{ V}$	13	15	17	V
V_{GATE-L}	Gate Low Voltage	$V_{DD} = 15\text{ V}$, $I_O = 100\text{ mA}$			1.5	V
V_{GATE-H}	Gate High Voltage	$V_{DD} = 13\text{ V}$, $I_O = 100\text{ mA}$	8			V
t_r	Gate Rising Time	$V_{DD} = 15\text{ V}$, $C_L = 4.7\text{ nF}$, V_{OPFC} from 2 V to 9 V		70		ns
t_f	Gate Falling Time	$V_{DD} = 15\text{ V}$, $C_L = 4.7\text{ nF}$, V_{OPFC} from 9 V to 2 V		60		ns

OTP

T_{OTP-ON}	Over-Temperature Protection (Note 3)			140		$^\circ\text{C}$
ΔT_{OTP}	Hysteresis (Note 3)			30		$^\circ\text{C}$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. This parameter, although guaranteed by design, is not 100% production tested.

4. The setting range of resistance at the RI pin is between 53.3 k Ω and 10.7 k Ω .

5. Frequency of AC input should be <75 Hz.

6. The RLS and RGC setting suggestion follows the calculation result from application notes AN-4164 and AN-4165.

7. LPK specification is guaranteed at state of PFC working.

8. Pull the CM pin low to ground, ensuring $V_{CM} < 0.2\text{ V}$, to enable an individual channel.

THEORY OF OPERATION**Continuous Conduction Mode (CCM)**

The boost converter, shown in Figure 4, is the most popular topology for power factor correction in AC-DC power supplies. This popularity can be attributed to the continuous input current waveform provided by the boost inductor and the boost converter's input voltage range low down to 0 V. These fundamental properties make close-to-unity power factor easier to achieve.

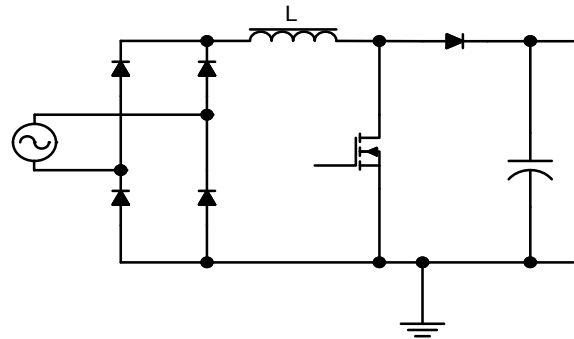


Figure 4. Basic PFC Boost Converter

The boost converter can operate in Continuous Conduction Mode (CCM) or in Boundary Conduction Mode (BCM). These two descriptive names refer to the current flowing in the energy storage inductor of the boost power stage.

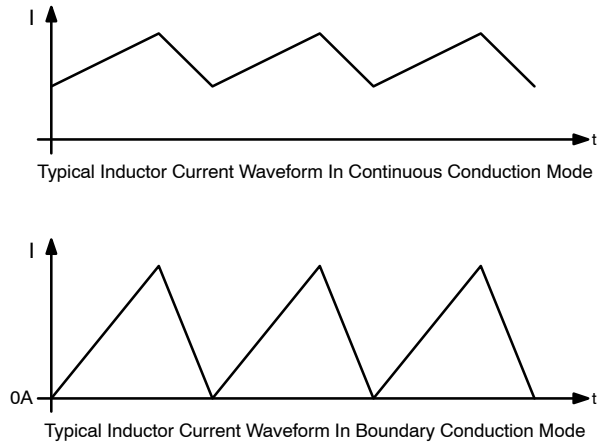


Figure 5. Basic PFC Boost Converter

As the names indicate, the inductor current in CCM is continuous and always above zero. In BCM, the new switching period is initiated when the inductor current returns to zero. There are many fundamental differences in CCM and BCM operations and the respective designs of the boost converter. The FAN9673 is design for CCM control, as Figure 5 shows. This method reduces inductor current ripple because the start current of each cycle is not 0 A typically. The ripple is controlled by the operation frequency and inductance design. This characteristic makes the peak current in the power semiconductor devices lower.

Gain Modulator (IA, LPK, VEA)

The FAN9673 employs two control loops for power factor correction: a current control loop and a voltage control loop. The current control loop shapes inductor current, as shown in Figure 6, through a current command, I_{MO} , from the gain modulator.

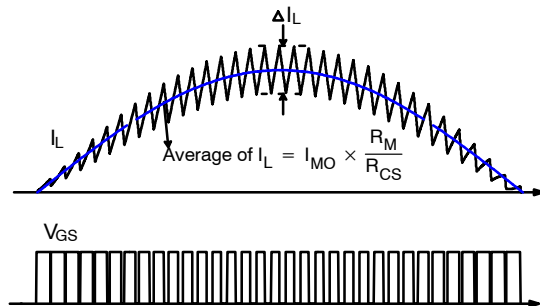


Figure 6. CCM PFC Operation Waveforms

The gain modulator is the block that provides the reference to control PFC input current. The output signal of the gain modulator, I_{MO} , is a function of V_{VEA} , I_{IAC} , and V_{LPK} ; as shown in the Figure 7.

These are the three inputs to the gain modulator:

- I_{IAC} : A current representing the instantaneous input voltage (amplitude and wave shape) to the PFC. The rectified AC input sine wave is converted to a proportional current via a resistor and fed into the gain modulator. A sampling mechanism on I_{IAC} minimizes ground noise, important in high-power, switching-power conversion environment. The gain modulator responds linearly to I_{IAC} .
- V_{LPK} : Voltage proportional to the peak-voltage output of the bridge rectifier when the PFC is working. The signal is the output of peak-detect circuit detecting from the I_{AC} . This factor of the gain modulator is input-voltage feed-forward control. This voltage information is not valid when the PFC is not working.
- V_{VEA} : The output of the voltage error amplifier. The gain modulator responds linearly to variations of this voltage. The output of the gain modulator is a current signal, I_{MO} , as eq. 1:

$$I_{MO} = K \times \frac{I_{AC} \times V_{VEA}}{V_{LPK}^2} \quad (\text{eq. 1})$$

where the K term is about 0.8 for $V_{IR} < 1.5$ V and 3.2 for $V_{IR} > 3.5$ V respectively.

The current signal, I_{MO} , is in the form of a full-wave rectified sinusoid at twice of the line frequency. The gain modulator forms the reference for the current-loop and ultimately controls the instantaneous current drawn from the power line.

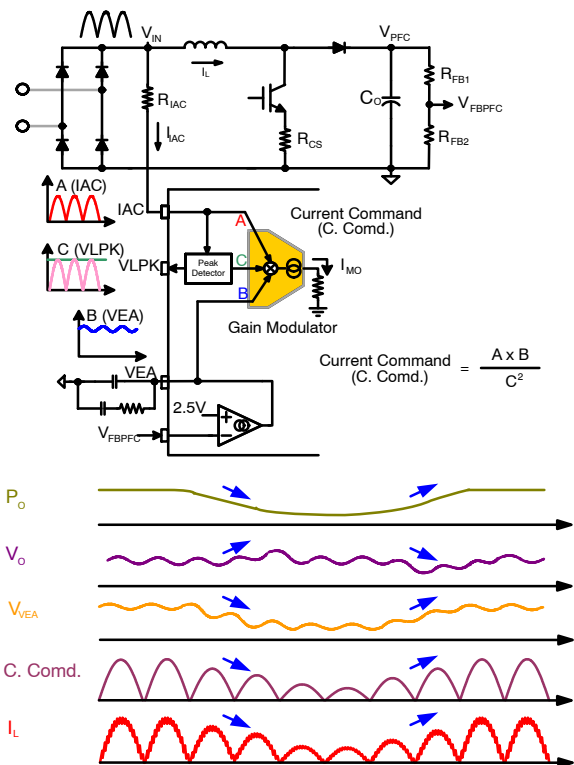


Figure 7. Input of Gain Modulation

Current Balance

Current matching of different channel is an important topic of multi-channel control. In FAN9673, control of current in each channel is based on sensed signal V_{CS} to track the current command from the gain modulator, as shown in Figure 8.

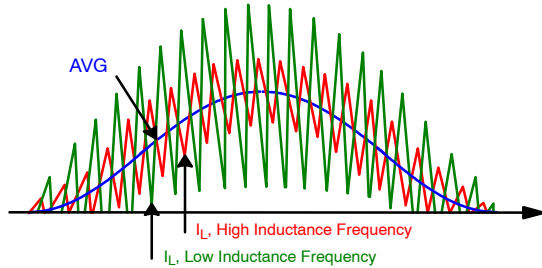


Figure 8. Average Current Mode Control

The main factors to balance current in each channel are layout and device tolerance. The tolerance of the shunt resistor for the current sense is especially important. If the feedback signal, V_{CS} , has large deviation due to the tolerance of the sense resistor, the current of the channels tends to be unbalanced. High precision resistors are recommended.

High-power applications implies current values are high, so the distance of layout trace between the current sense resistors and the controller or power ground (negative of output capacitor) to IC ground is important, as shown in Figure 9. The longer trace and large current make the offset voltage and ground bounce differ significantly for different channels. Decreasing the deviation help balancing different channels. Please check the layout guidance in application notes [AN-4164](#) or [AN-4165](#).

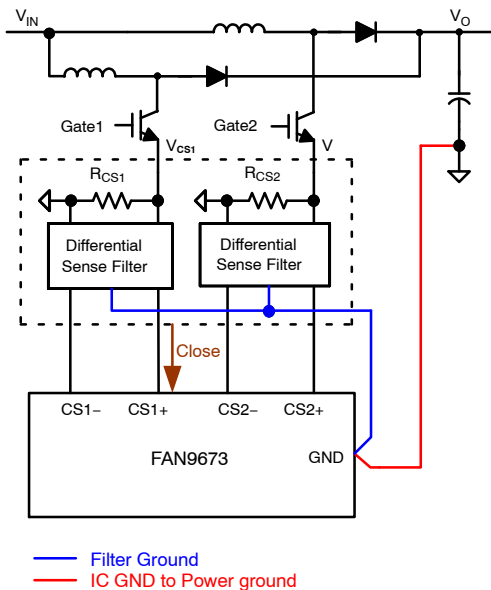


Figure 9. Current Balance Factors

Interleaving

The FAN9673 controller is used to control three-channel boost converters connected in parallel. The controller operates in average-current mode and supports Continuous Conduction Mode (CCM). Each channel affords one-third the power when the system operates close to full load or when channel management is disabled.

Parallel power processing increases the number of power components, but the current rating of independent channels is reduced, allowing power semiconductors with lower current ratings to be applied.

The switches of the three boost converters can operate at three-channel with 120° out-of-phase or two-channel with 180° out-of-phase (one channel disable at light load). The interleaving controller can reduce the total ripple current of input. Simultaneously, the output current ripple of each channel is evenly distributed and sequentially rippled on the output capacitor, which can extend the life of the capacitor.

Channel Management 2/3: CM Control

The CM pin is used for controlling channel management. The channel management is realized by changing a gain, acting as changing relative weighting, for the current command. The relationship of CM and the gain of the slave channel is shown in Figure 10. The level of CM set the threshold of power level, representing by V_{VEA} , for reducing the current command for the slave PFC. The FAN9673 starts to reduce the current command ($I_{MO} \times R_M$) for channel 2/3 by $G_{ain2/3}$ from one to zero when the V_{VEA} level is lower than its CM level, as Figure 11 and Figure 12 show. The output power of the slave channel is reduced in response to reduction in current command. For example, when CM2 is set at 3 V and V_{VEA} is less than the CM2 voltage, the channel management block reduces the command for channel 2 as:

$$V_{gmi2+} = I_{MO} \times R_M \times G_{ain2} \quad (\text{eq. 2})$$

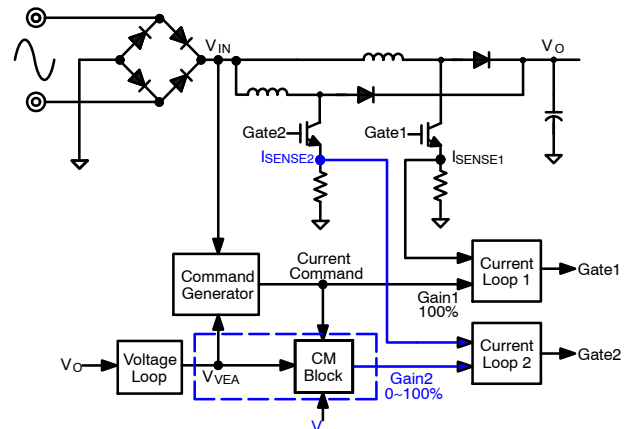


Figure 10. Current Balance Factors

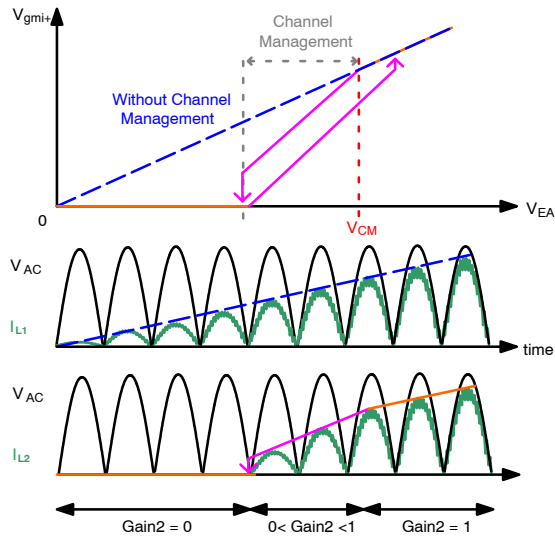
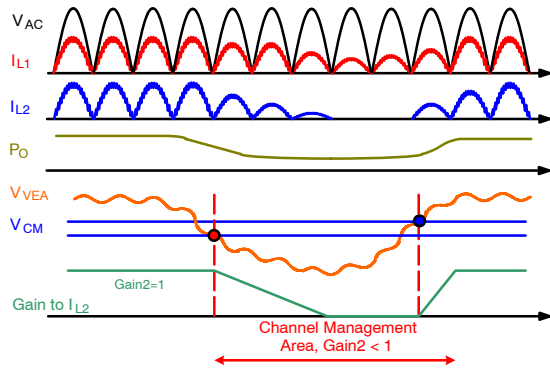
Figure 11. V_{VEA} and CM RelationshipFigure 12. V_{VEA} and V_{CM} Relationship in Channel Management Operation

Table 2 explains the phase and gain change of each channel when the PFC operates at various loads. The loading decreases the gain to the slave until it is disabled. The phase of Channel Management (CM) mode doesn't change when channel 3 is disabled. The behavior shown in Figure 13.

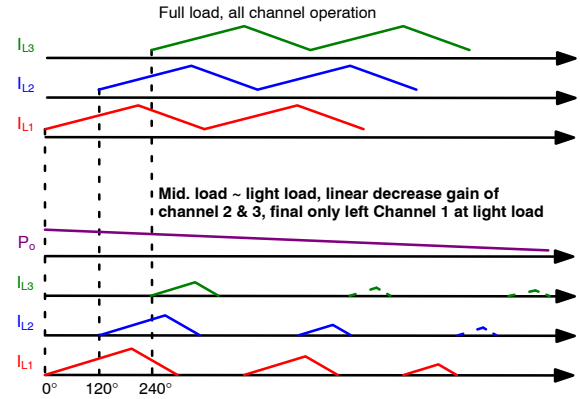


Figure 13. Phase and Gain Change of CM Control

Table 2. PHASE AND GAIN CHANGE OF CM CONTROL

CM (Channel Management)	Phase and Gain		
	Channel 1	Channel 2	Channel 3
Heavy Load (All Channel 100% Works)	0° (Gain1 = 1)	120° (Gain2 = 1)	240° (0 < Gain3 < 1)
Mid. Load (Channel 3 is Disabled)	0° (Gain1 = 1)	120° (0 < Gain2 < 1)	Disable (Gain3 = 0)
Light Load (Only Channel1 Left)	0° (Gain1 = 1)	Disable (Gain2 = 0)	Disable (Gain3 = 0)

Channel Management 2: External Control

Channel Management (CM) function can also be accessed by an MCU through the connection shown in Figure 14. CM pins have internal pull-up current source. If $V_{CM} > 4$ V, the channel is disabled. To enable the channel, make $V_{CM} = 0$ V, as shown in Figure 15.

The CM pin of the slave should be connected with a switch S_2 to ground. One pin of MCU must read the V_{VEA} signal to

determine when to turn on/off the slave channel. For example, as shown in Figure 16, two thresholds, $V_{P2-OFF-L}$ and $V_{P2-OFF-H}$, are set in MCU program. When $V_{VEA} < V_{P2-OFF-L}$, the slave PFC turns off. If $V_{VEA} > V_{P2-OFF-H}$, the slave PFC turns on.

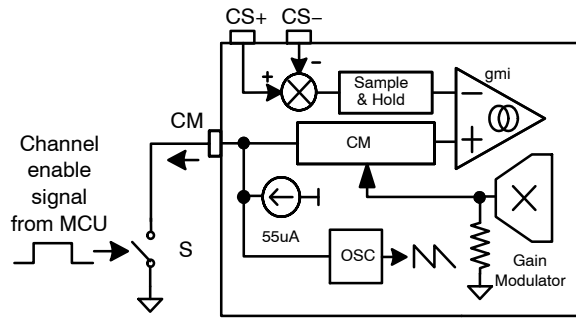


Figure 14. Channel Management by MCU

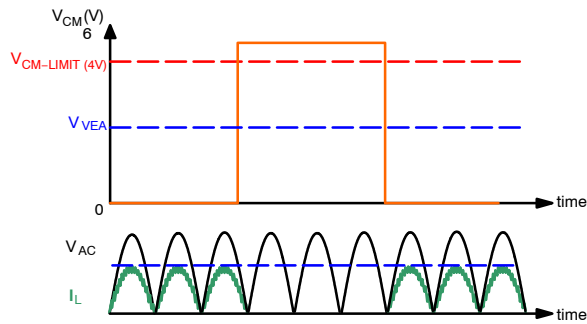


Figure 15. Channel Management by MCU

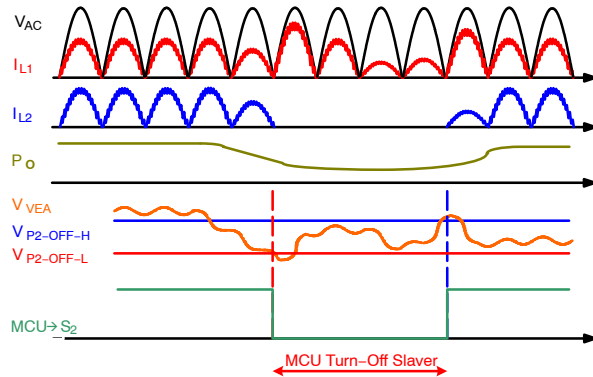


Figure 16. Channel Management by External Signal from MCU

When CM is accessed this way, relative phase of OPFC of each channel changes when the loading changes, as illustrated in Table 3 and Figure 17. When the MCU disables channel 3 at mid-load, the relative phase angle of channel 2 to channel 1 shifts from 120° to 180°. $G_{\text{ain}2/3}$ of each channel under this control method switches between 100% and 0%.

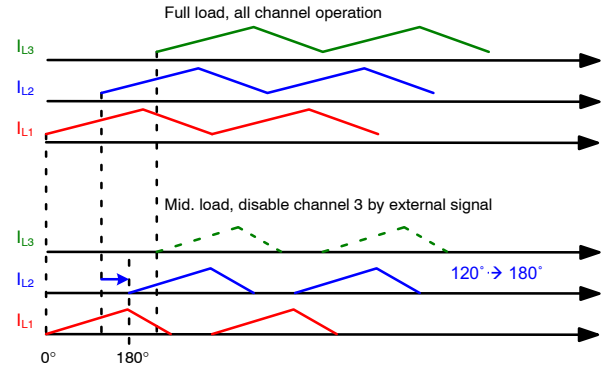


Figure 17. Phase Change under External Signal Control

Table 3. PHASE CHANGE OF EXTERNAL SIGNAL CONTROL

External Signal Control	Phase (Disable Channel: $V_{CM} > 4\text{ V}$, Enable Channel: $V_{CM} = 0\text{ V}$)		
	Channel 1	Channel 2	Channel 3
Heavy Load (All Channels Enabled)	0°	120°	240°
Mid. Load (Channel3 Disabled)	0°	180°	Disable ($V_{CM3} > 4\text{ V}$)
Light Load (Channel 2/3 Disabled)	0°	Disable ($V_{CM2} > 4\text{ V}$)	Disable ($V_{CM3} > 4\text{ V}$)
Disable All System	$V_{CM1} > 4\text{ V}$, All Channels Disabled		

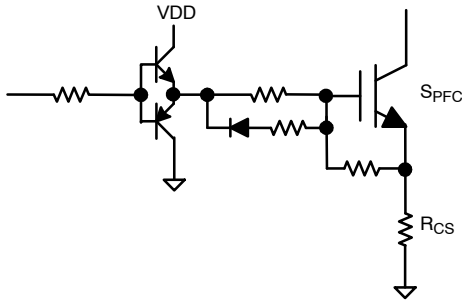


Figure 20. Gate Drive Circuit

Differential Current Sensing (CS+, CS-)

Switching noise problems in interleaved PFC control is more critical than on a single channel, especially for current sensing. The FAN9673 uses a differential amplifier to eliminate switching noise from other channels. The FAN9673 has three groups of differential current-sensing pins. The CSn+ and CSn- are the inputs of the internal differential amplifiers. This makes the PFC more stable in higher-power applications and eliminates switching noise from other channels. As Figure 21 shows, ground bounce can be decreased by a differential sense function.

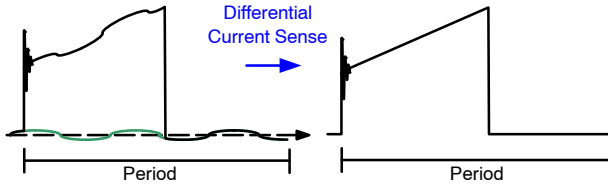


Figure 21. Gate Drive Circuit

Linear Predict Function (GC & LS)

Current sense signal reflects inductor current only when OPFC is on. The linear predict function is used to emulate the behavior of inductor current when the OPFC is off. Resistor on the LS pin is used to set equivalent inductance value for the internal emulator. Resistor on the GC pin is used to align sensed input voltage (IAC) and output voltage (FBPFC) signals. Values of those resistors can be determined by:

$$R_{LS} = \frac{L_{PFC}}{1.5 \times 10^{-9} \times R_{CS} \times \frac{(R_{FB1} + R_{FB2} + R_{FB3})}{R_{FB3}}} \quad (\text{eq. 5})$$

$$R_{GC} = \frac{6 \times 10^6}{\frac{(R_{FB1} + R_{FB2} + R_{FB3})}{R_{FB3}}} \quad (\text{eq. 6})$$

Care must be taken that RLS value need to be within 12~87 kΩ.

Current-Limit Protection

The FAN9673 includes three factors that limits current to manage OCP and inductor saturation: V_{VEA} limit, V_{ILIMIT} , and $V_{ILIMIT2}$. The current-limit thresholds, $V_{ILIMIT1}$ and

$V_{ILIMIT2}$, are configurable through ILIMIT and ILIMIT2 pins.

Power (Normal State)

In the normal case, average input power is controlled by the command V_{VEA} . When V_{VEA} rises to 5.6 V, it is internally clamped. Input power can't increase further.

Current Limit 1 (Abnormal State)

The current command from the gain modulator is $K \times I_{AC} \times V_{VEA} / V_{LPK}^2$. In abnormal state, such as AC cycle miss and recover in a short period, the V_{LPK} has a delay before returning to the original level. This delay makes the current command increased. If the command is greater than the limit clamp level, V_{ILIMIT} , current command will be clamped, as shown in Figure 22 and Figure 23. The peak current of this state can be used as the maximum current for inductor design, assuring inductor is not saturated.

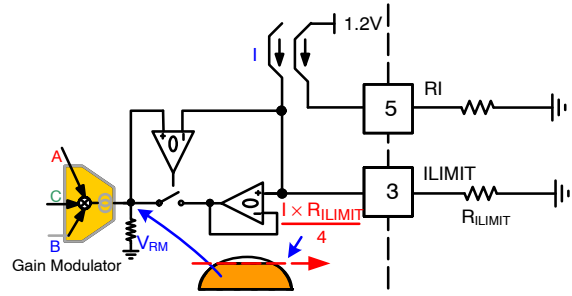


Figure 22. Current Command Limit by ILIMIT

Current Limit 2 (Saturation State)

Use 80% ~ 90% of the maximum current of the switch device to serve as the saturation protection. V_{LIMIT2} is a cycle-by-cycle limit.

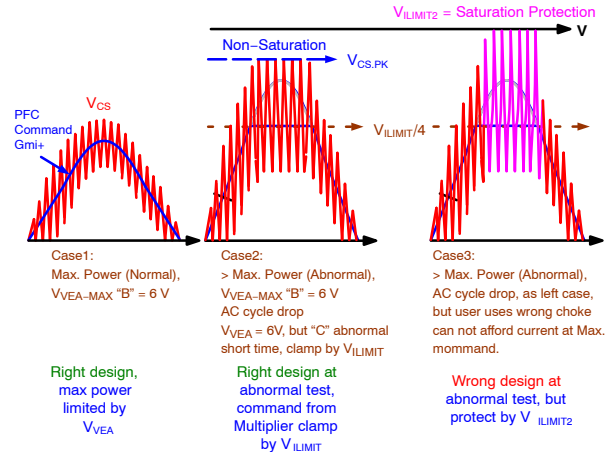


Figure 23. ILIMIT and ILIMIT2 Setting

Programmable PFC Output Voltage (PVO)

In some cases, decreasing the PFC output voltage can improve efficiency of the PFC stage. The PVO pin is used to program output voltage, as shown in Figure 24. An

external voltage signal, from MCU or other source, is provided to PVO pin.

This function is enabled when $V_{PVO} > 0.5$ V. Upon enabled, V_{FBPFC} regulation target becomes:

$$V_{FBPFC} = 2.5 \text{ V} - \left[\frac{V_{PVO}}{4} \right] \quad (\text{eq. 7})$$

For instance, if PVO input is 1 V, $R_{FB1} + R_{FB2} = 3.7 \text{ M}\Omega$, and $R_{FB3} = 23.7 \text{ k}\Omega$, V_{FBPFC} will be regulated to 2.25 V, making PFC $V_O = 354 \text{ V}$.

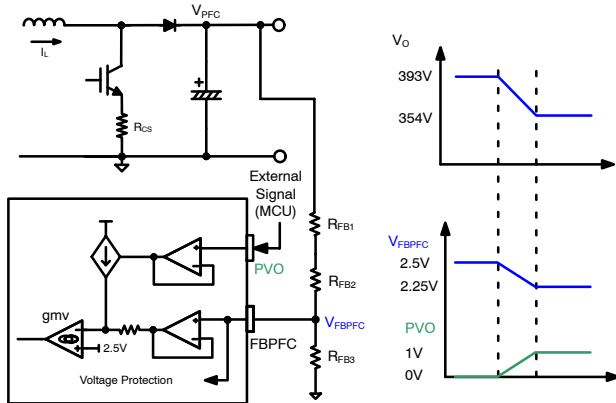


Figure 24. Programmable PFC Output Voltage

RDY Function and AC Line Off/AC “SAG”

The ready (RDY) function is used to signal the MCU that the PFC stage is ready and the downstream power stage can start to operate. When the feedback voltage on FBPFC rises above 2.4 V, V_{RDY} signal pulls HIGH as shown in Figure 25.

If the AC line is OFF (or AC signal drops for a long time), the FAN9673 enters brown-out and V_{RDY} pulls LOW to indicate to the MCU that the power stage should stop, as shown in Figure 26.

When the AC signal drops for only a short time (i.e. 1~1.5 AC cycles), brown-out is not triggered and V_{FBPFC} may not drop too much. In this case, RDY will not go LOW as shown in Figure 27.

AC “sag” means the AC drops to a low level, such as 110 V / 220 V $\rightarrow$ 40 V. AC “missing” means the AC drops to 0 V. If AC drops, the PFC attempts to transfer energy to V_O before V_O drops to the 50% level. If AC is 0 V, the PFC can’t transfer energy. If the level reaches 50%, the PFC stops, and FAN9673 resets and waits for AC to return.

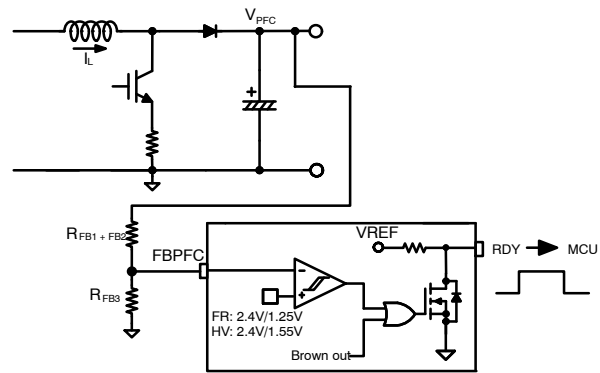


Figure 25. RDY Function to MCU

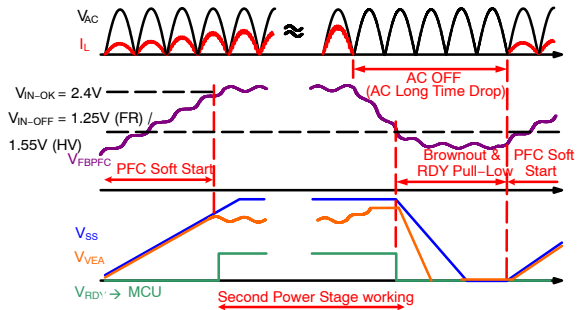


Figure 26. When AC Drops for a Long Time

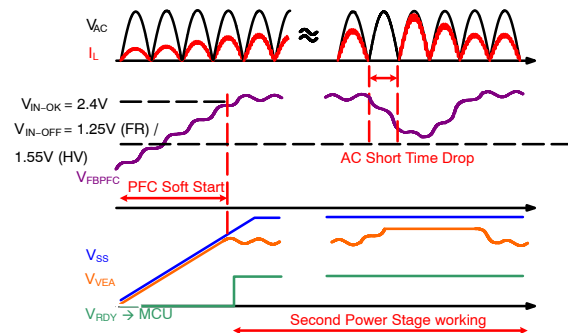


Figure 27. AC Drops Briefly

Typical Performance Characteristics

Typical characteristics are provided at $T_A = 25^\circ\text{C}$ and $V_{DD} = 15\text{ V}$ unless otherwise noted.

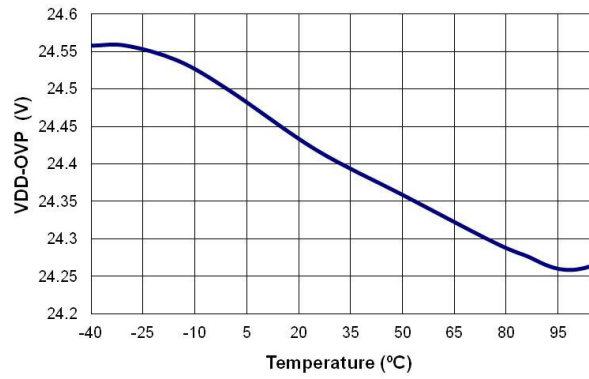


Figure 30. I_{DD-OP} vs. Temperature

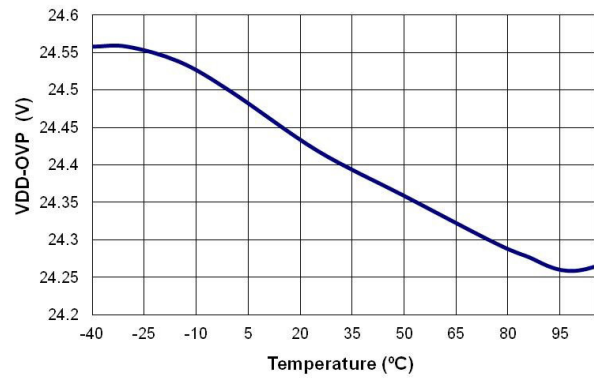


Figure 31. V_{DD-OVP} vs. Temperature

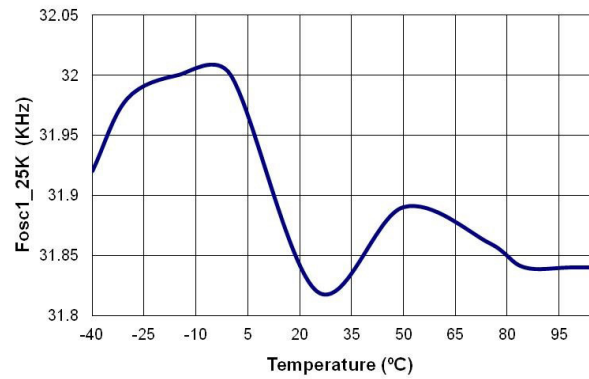


Figure 32. f_{osc} vs. Temperature

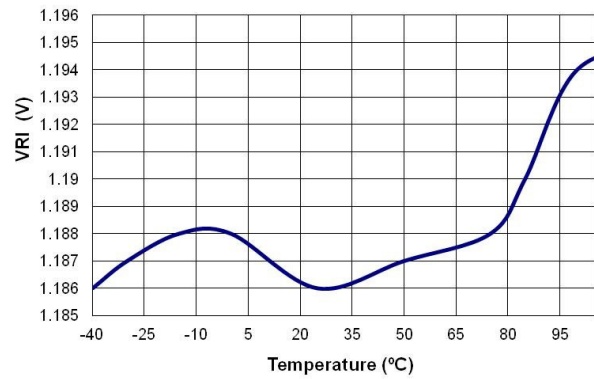


Figure 33. V_{RI} vs. Temperature

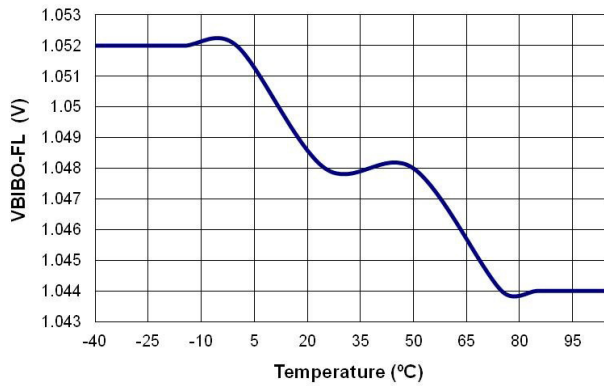


Figure 34. $V_{BIBO-FL}$ vs. Temperature

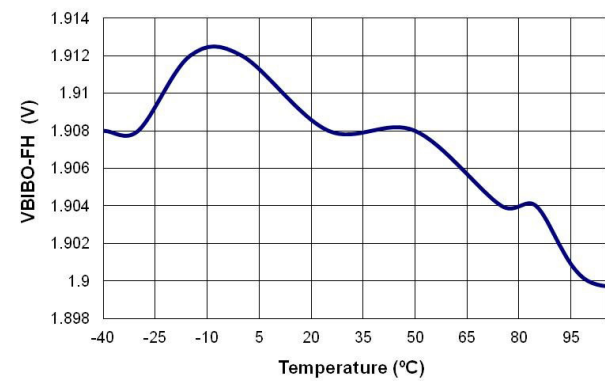


Figure 35. $V_{BIBO-FH}$ vs. Temperature

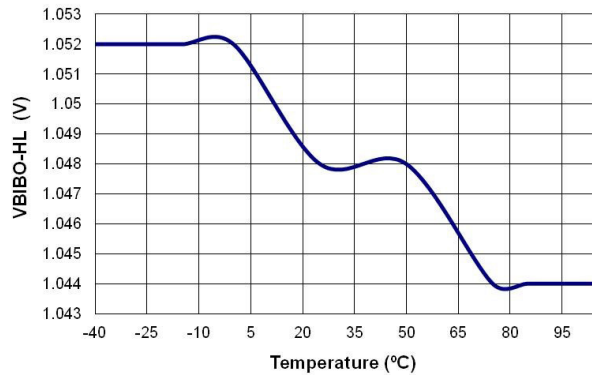


Figure 36. $V_{BIBO-HL}$ vs. Temperature

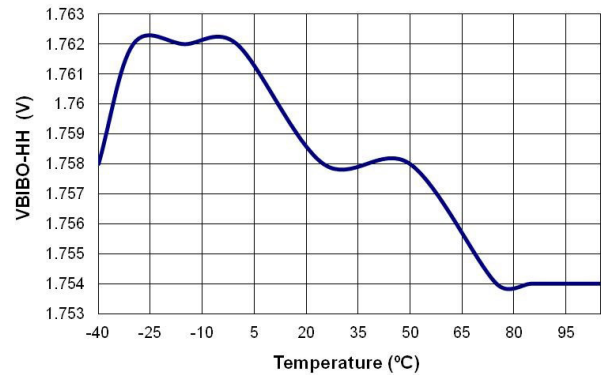
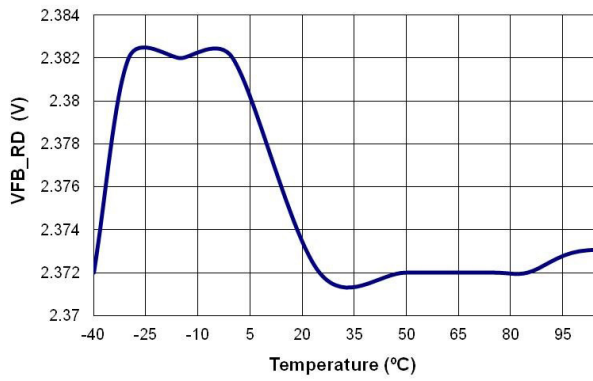
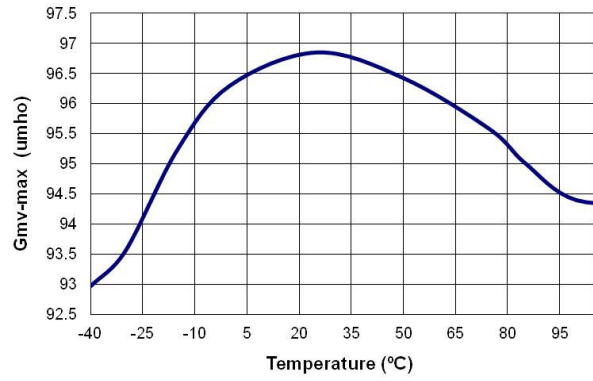
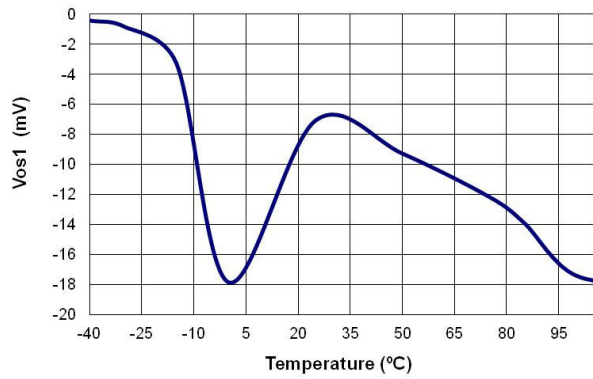
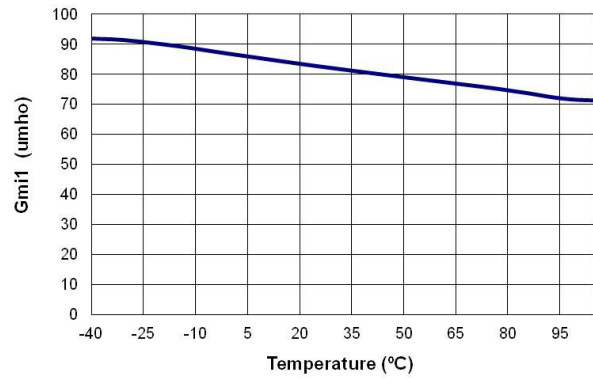
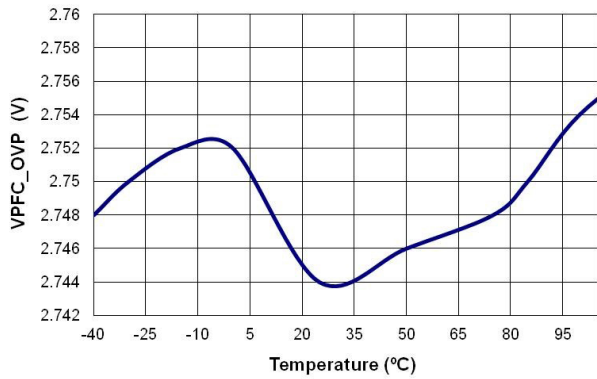
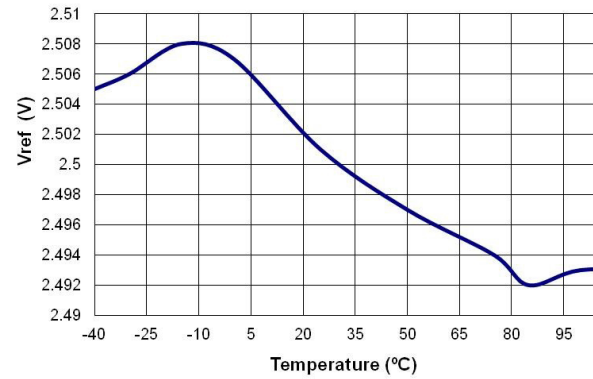
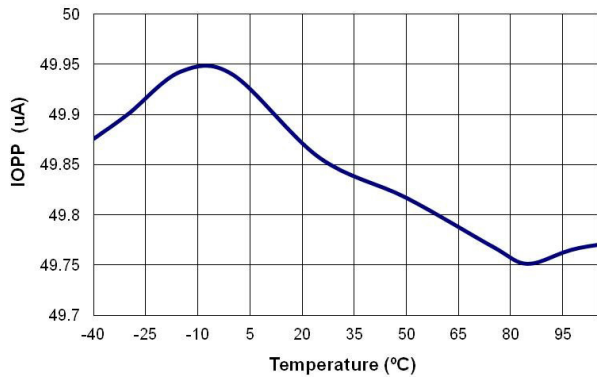
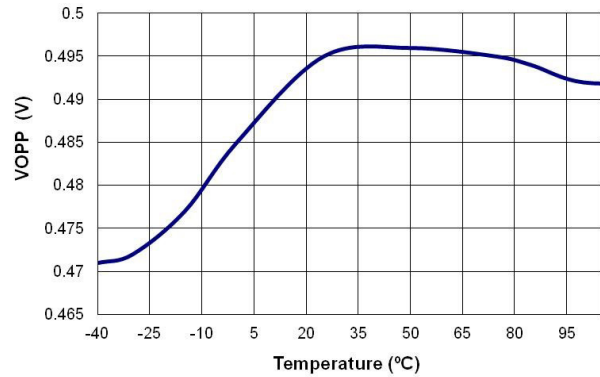


Figure 37. $V_{BIBO-HH}$ vs. Temperature

Typical Performance Characteristics (continued)

Typical characteristics are provided at $V_{DD} = 15\text{ V}$ unless otherwise noted.

Figure 38. $V_{FBPFC-RD}$ vs. TemperatureFigure 39. G_{mV-MAX} vs. TemperatureFigure 40. V_{OFFSET} vs. TemperatureFigure 41. G_{M1} vs. TemperatureFigure 42. $V_{PFC-OVP}$ vs. TemperatureFigure 43. V_{REF} vs. TemperatureFigure 44. I_{LIMIT} vs. TemperatureFigure 45. V_{LIMIT} vs. Temperature

Typical Performance Characteristics (continued)

Typical characteristics are provided at $V_{DD} = 15\text{ V}$ unless otherwise noted.

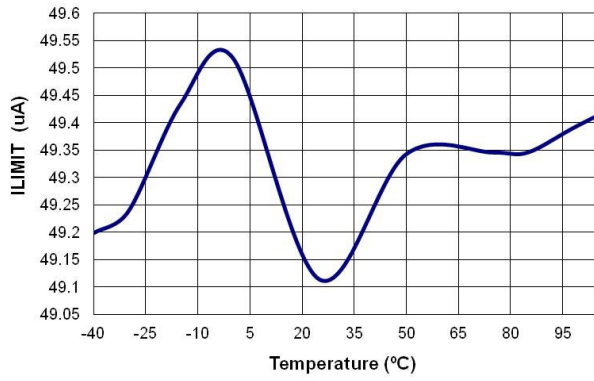
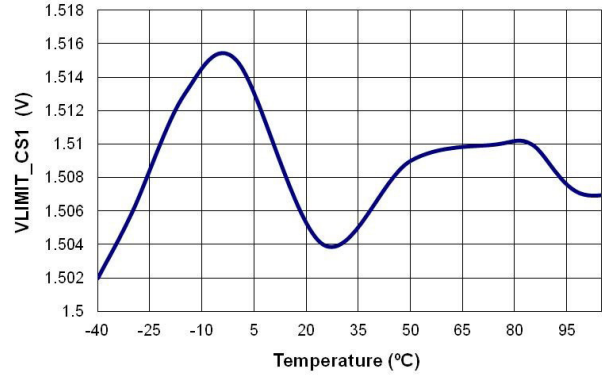
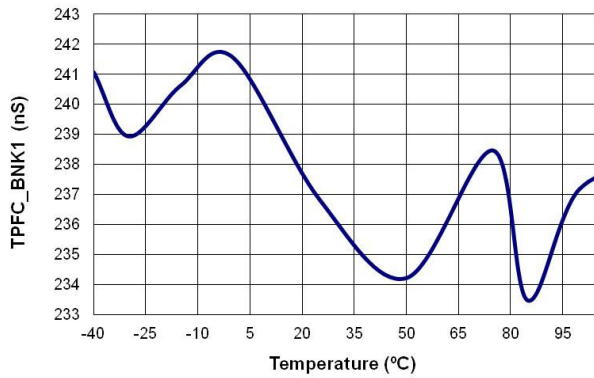
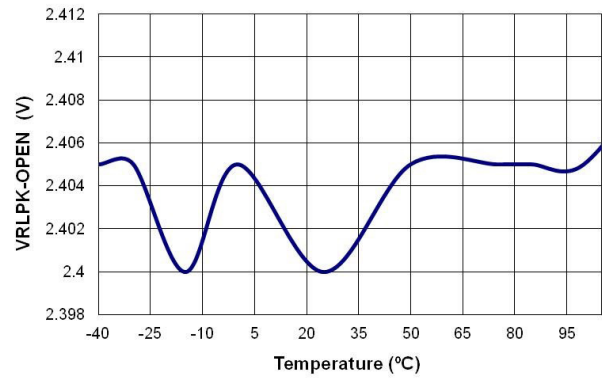
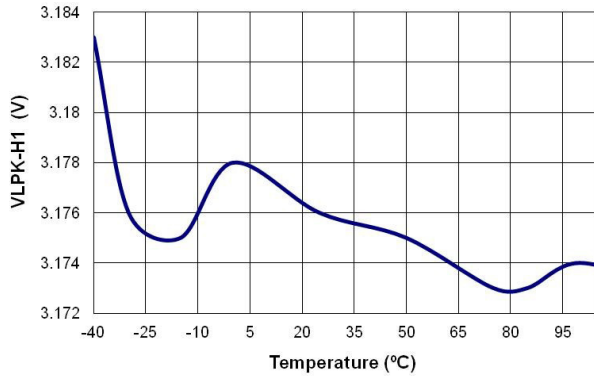
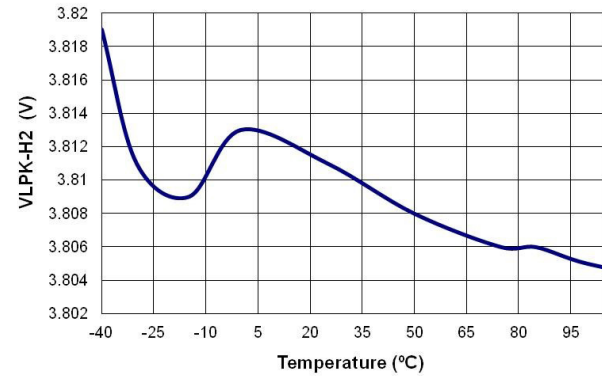
Figure 46. $I_{ILIMIT2}$ vs. TemperatureFigure 47. $V_{ILIMIT2-CS1}$ vs. TemperatureFigure 48. $t_{PFC-BNK}$ vs. TemperatureFigure 49. $V_{RLPK-OPEN}$ vs. TemperatureFigure 50. V_{LPK-H1} vs. TemperatureFigure 51. V_{LPK-H2} vs. Temperature

Table 5. TYPICAL APPLICATION CIRCUIT

Application	Output Power	Input Voltage	Output Voltage/Output Current
Single-Stage, Three-Channel PFC	5000 W	180 ~ 264 V _{AC}	393 V/12.72 A

Features

- 180 V_{AC} ~264 V, Three-Channel PFC Using FAN9673
- Switch-Charge Technique of Gain Modulator for Better PF and Lower THD
- 40 kHz Low Switching Frequency Operation with IGBT
- Protections: Over-Voltage Protection (OVP), Under-Voltage Protection (UVP), and Over-Current Protection (I_{LIMIT}), Inductor Saturation Protection (I_{LIMIT2})

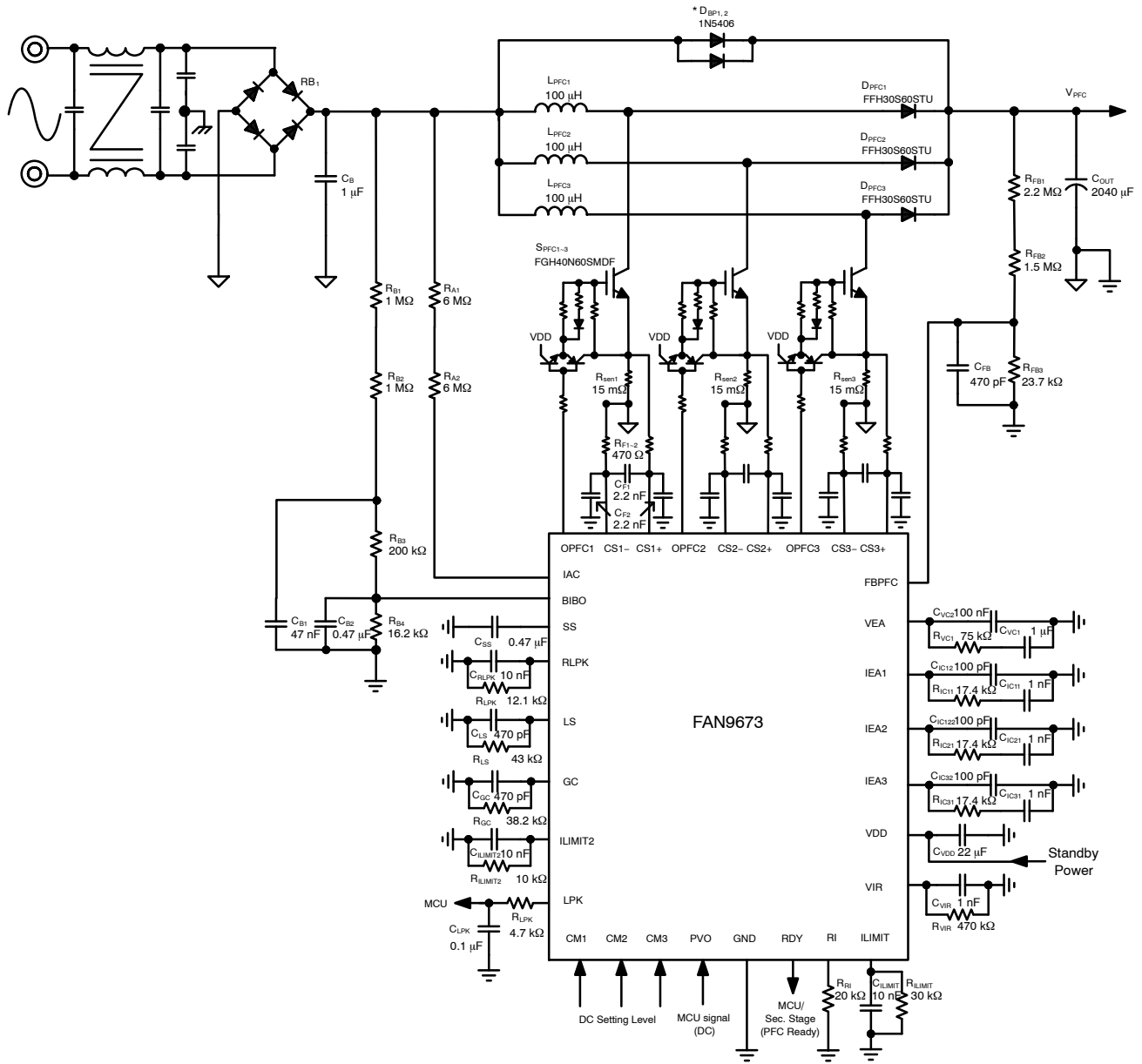


Figure 52. Schematic of Design Example

FAN9673

Specification

- V_{DD} Maximum Rating: 20 V
- V_{DD} OVP: 24 V
- V_{CC} UVLO: 10.3 V/12.8 V
- PVO: 0 V ~ 1 V
- PFC Soft-Start: $C_{SS} = 0.47 \mu\text{F}$
- Brown-In/Out: 175 V/165 V

- Switching Frequency: 40 kHz
- V_{FBPFC} for RDY: 2.4 V/1.55 V (96% / 62%)
- R_{IAC} : 12 M Ω

Inductor Schematic Diagram

- Core: QP2925H (3C94)
- Bobbin: 4 Pins

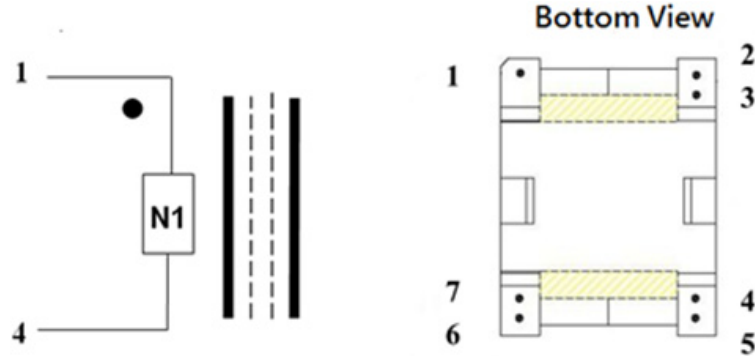


Figure 53. Inductor Schematic Diagram

Table 6. WINDING SPECIFICATION

No.	Winding	Pin (S → F)	Wire	Turns	Winding Method
1	N1	1 → 4	0.1 ϕ × 40 *1	46	Solenoid Winding
2	Insulation: Polyester Tape t = 0.025 mm, 2-Layer				
3	Copper-Foil 1.2T to PIN3				

Table 7. MOSFET AND DIODE REFERENCE SPECIFICATION

IGBT's	
Voltage Rating	
600 V (IGBT)	FGH40N60SMDF
Boost Diodes	
600 V	FFH30S60STU

Typical Performance

Table 8. EFFICIENCY

	25% Load	50% Load	75% Load	100% Load
180 V/50 Hz	96.5%	96.5%	96.5%	96.2%
220 V/50 Hz	97.0%	97.1%	97.2%	97.1%
264 V/50 Hz	97.6%	97.9%	97.7%	97.6%

Table 9. POWER FACTOR

	25% Load	50% Load	75% Load	100% Load
180 V/50 Hz	0.9912	0.9947	0.9971	0.9974
220 V/50 Hz	0.9800	0.9868	0.9905	0.9924
264 V/50 Hz	0.9365	0.9369	0.9526	0.9600

Table 10. TOTAL HARMONIC DISTORTION

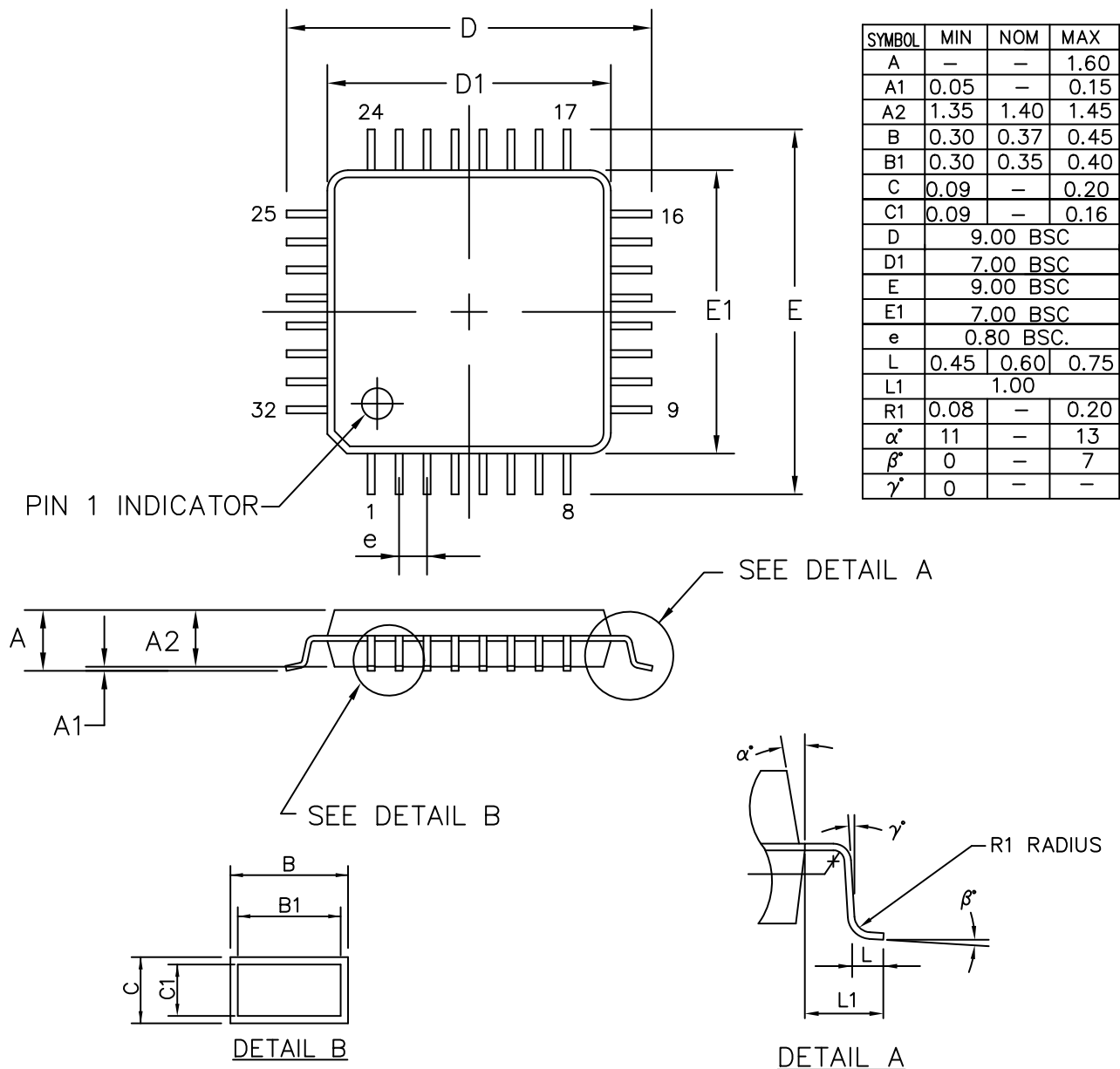
	25% Load	50% Load	75% Load	100% Load
180 V/50 Hz	10.55%	9.17%	6.62%	6.40%
220 V/50 Hz	14.32%	14.36%	12.55%	11.26%
264 V/50 Hz	25.85%	33.22%	29.59%	27.29%

System Design Precautions

- Pay attention to the inrush current when AC input is first connected to the boost PFC convertor. It is recommended to use NTC and a parallel connected relay circuit to reduce inrush current.
- Add bypass diode to provide a path for inrush current when PFC start up.
- The PFC stage is normally used to provide power to a downstream DC-DC or inverter. It's recommend that downstream power stage is enabled to operate at full load once the PFC output voltage has reaches a level close to the specified steady-state value.
- The PVO function is used to change the output voltage of PFC, V_{PFC} . The V_{PFC} should be kept at least 25 V higher than V_{IN} .

LQFP-32, 7x7
CASE 561AB-01
ISSUE O

DATE 19 JUN 2008



ALL DIMENSIONS IN MM

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